CORRIGENDUM

OPTICAL AND ELECTRONIC PROPERTIES OF M_2Si ($M = Mg, Ca$ AND Sr) GROWN BY REACTIVE DEPOSITION TECHNIQUE

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Nikolay G. Galkin should be included as one of the authors. K. N. Galkin and T. V. Turchin are more precisely shown as Konstantin N. Galkin and Taras V. Turchin to avoid confusion.

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